

QSiC™ 1700V SiC Schottky Diode

VDC	1700 V
Q _C	515 nC
I _F	50 A
T _{j,max}	175 °C

Features

- Unipolar rectifier with surge current
- Zero reverse recovery current
- Fast, temperature-independent switching
- Avalanche tested to 1250mJ*
- All parts tested to greater than 1,870V

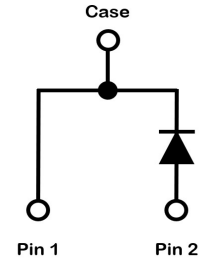
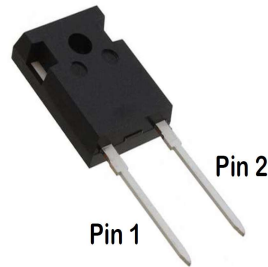
Benefits

- Near zero switching loss
- Higher efficiency
- Reduced heat sink requirements
- Easy to parallel

Applications

- Switch mode power supplies, UPS
- DC/DC Converters
- Solar Inverters
- EV charging stations

Package



Part #	Package	Marking
GP3D050B170B	TO-247-2L	3D050B170

PRELIMINARY



Maximum Ratings, at T_J=25 °C, unless otherwise specified

Characteristics	Symbol	Conditions	Values	Unit
Continuous forward current	I _F **	T _C =25 °C, T _J =175 °C	151	A
		T _C =125 °C, T _J =175 °C	83	
		T _C =150 °C, T _J =175 °C	55	
Surge non-repetitive forward current sine halfwave	I _{FSM}	T _C =25 °C, t _p =8.3 ms	360	A
		T _C =110 °C, t _p =8.3 ms	324	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t _p =10 μs	1475	A
i ² t value	∫i ² dt	T _C =25 °C, t _p =8.3 ms	538	A ² s
		T _C =110 °C, t _p =8.3 ms	436	
Repetitive peak reverse voltage	V _{RRM}	T _J =25 °C	1700	V
Diode dv/dt ruggedness	dv/dt	Turn-on slew rate, repetitive	200	V/ns
Power dissipation	P _{tot} **	T _C =25 °C	789	W
Operating junction & storage temperature	T _J , T _{storage}	Continuous	-55...175	°C
Soldering temperature	T _{solder}	Wave soldering leads	260	°C
Mounting torque		M3 Screw	1	N-m

Notes:

* EAS of 1250 mJ is based on starting T_J = 25°C, L = 1.0 mH, I_{AS} = 50 A, V = 50 V.

** Typical R_{thJC} used

Electrical Characteristics, at $T_j=25\text{ }^{\circ}\text{C}$, unless otherwise specified

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
DC blocking voltage	V_{DC}	$I_R=200\mu\text{A}$, $T_j=25\text{ }^{\circ}\text{C}$	1700	-	-	V
Breakdown voltage	V_{BR}	$I_R=5\text{mA}$, $T_j=25\text{ }^{\circ}\text{C}$	1870	-	-	V
Diode forward voltage	V_F	$I_F=50\text{A}$, $T_j=25\text{ }^{\circ}\text{C}$	-	1.52	1.65	V
		$I_F=50\text{A}$, $T_j=125\text{ }^{\circ}\text{C}$	-	1.92	-	
		$I_F=50\text{A}$, $T_j=175\text{ }^{\circ}\text{C}$	-	2.27	2.80	
Reverse current	I_R	$V_R=1,700\text{V}$, $T_j=25\text{ }^{\circ}\text{C}$	-	12	200	μA
		$V_R=1,870\text{V}$, $T_j=25\text{ }^{\circ}\text{C}$	-	42	-	
		$V_R=1,700\text{V}$, $T_j=125\text{ }^{\circ}\text{C}$	-	182	-	
		$V_R=1,700\text{V}$, $T_j=175\text{ }^{\circ}\text{C}$	-	845	2000	
Total capacitive charge	Q_C	$V_R=1700\text{V}$, $T_j=25\text{ }^{\circ}\text{C}$	-	515	-	nC
Total capacitance	C	$V_R=1\text{V}$, $f=1\text{ MHz}$	-	3511	-	pF
		$V_R=800\text{V}$, $f=1\text{ MHz}$	-	219	-	
		$V_R=1700\text{V}$, $f=1\text{ MHz}$	-	216	-	

Thermal Characteristics

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
Thermal resistance, junction-case	R_{thJC}	-	-	0.19	0.23	$^{\circ}\text{C/W}$

Typical Performance

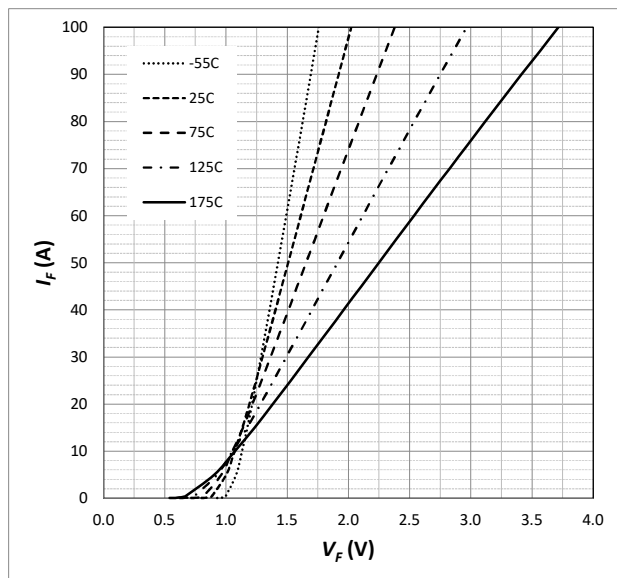


Fig. 1 Forward Characteristics (parameterized on T_j)

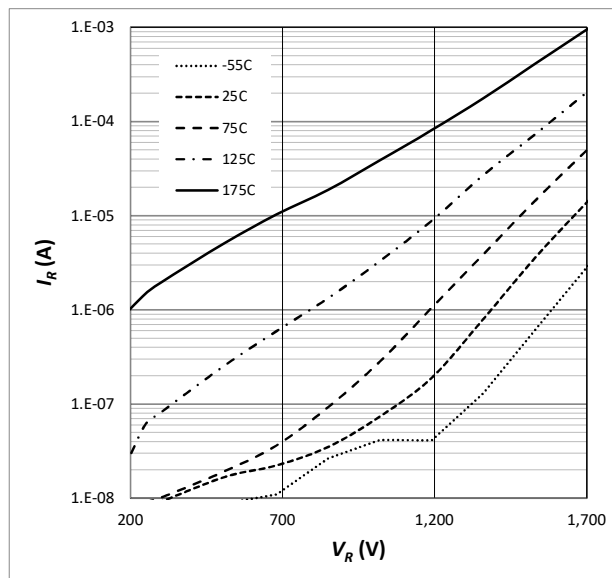


Fig. 2 Reverse Characteristics (parameterized on T_j)

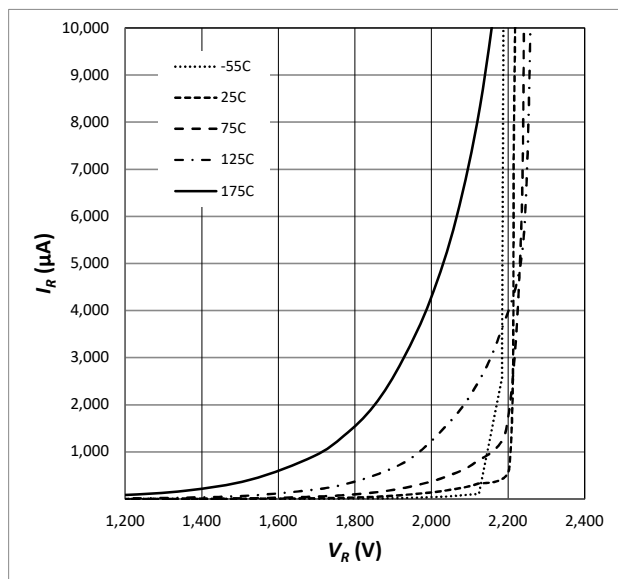


Fig. 3 Reverse Characteristics (parameterized on T_j)

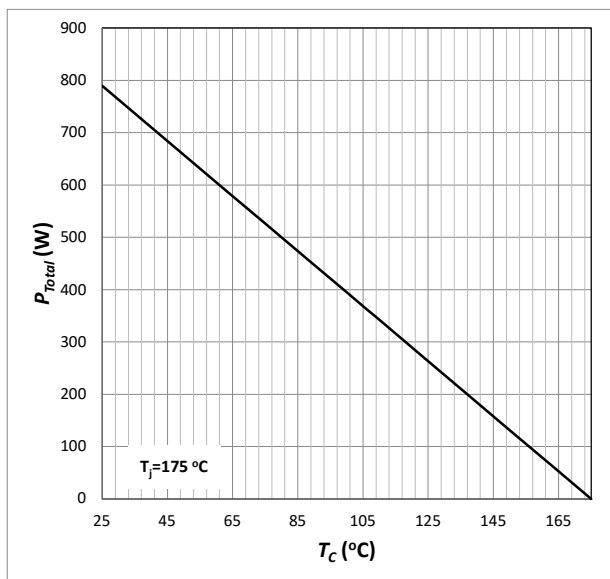


Fig. 4 Power Derating

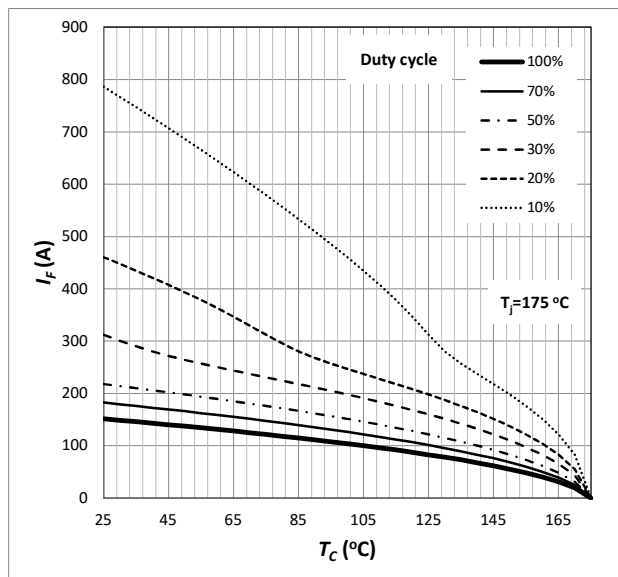


Fig. 5 Current Derating

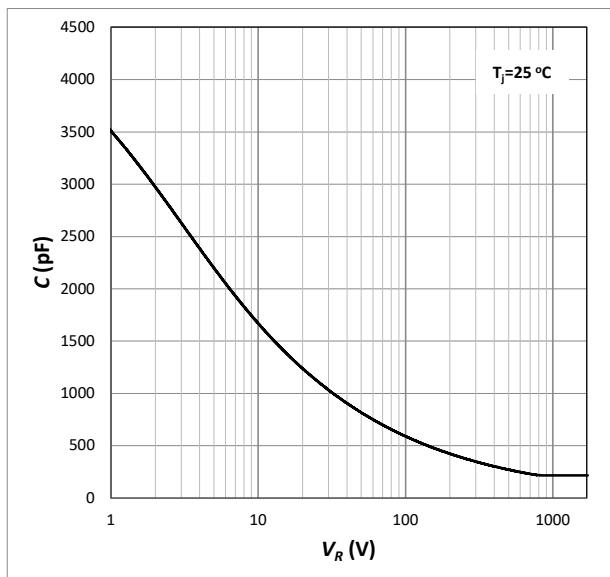
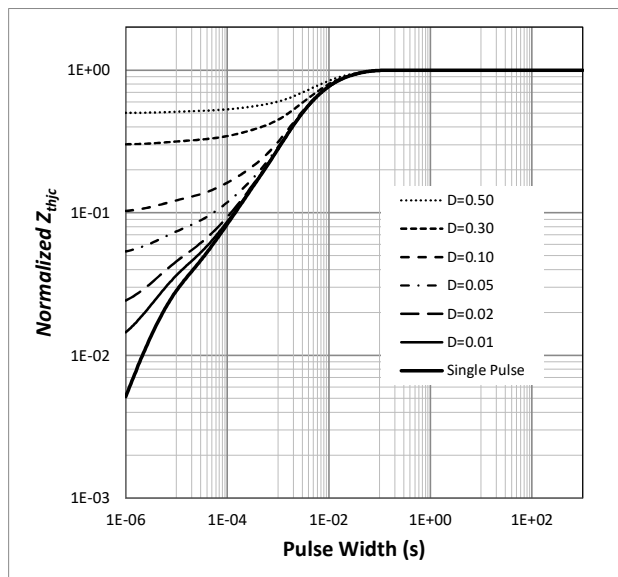
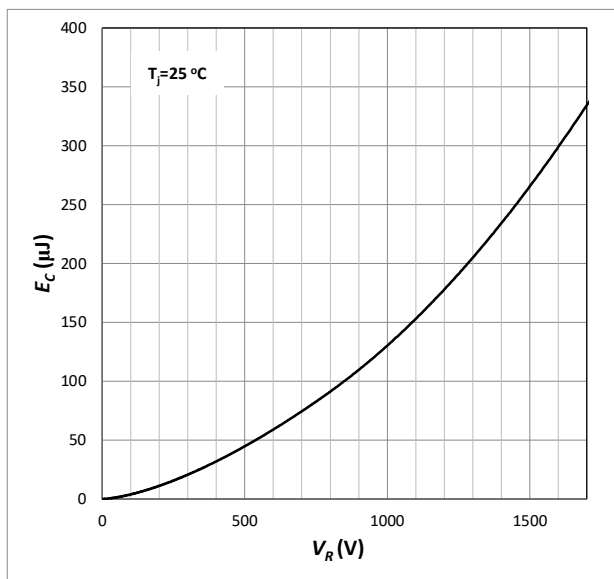
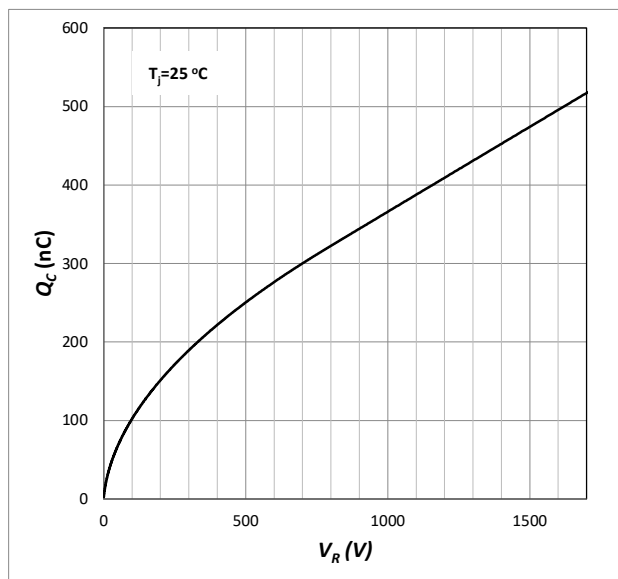


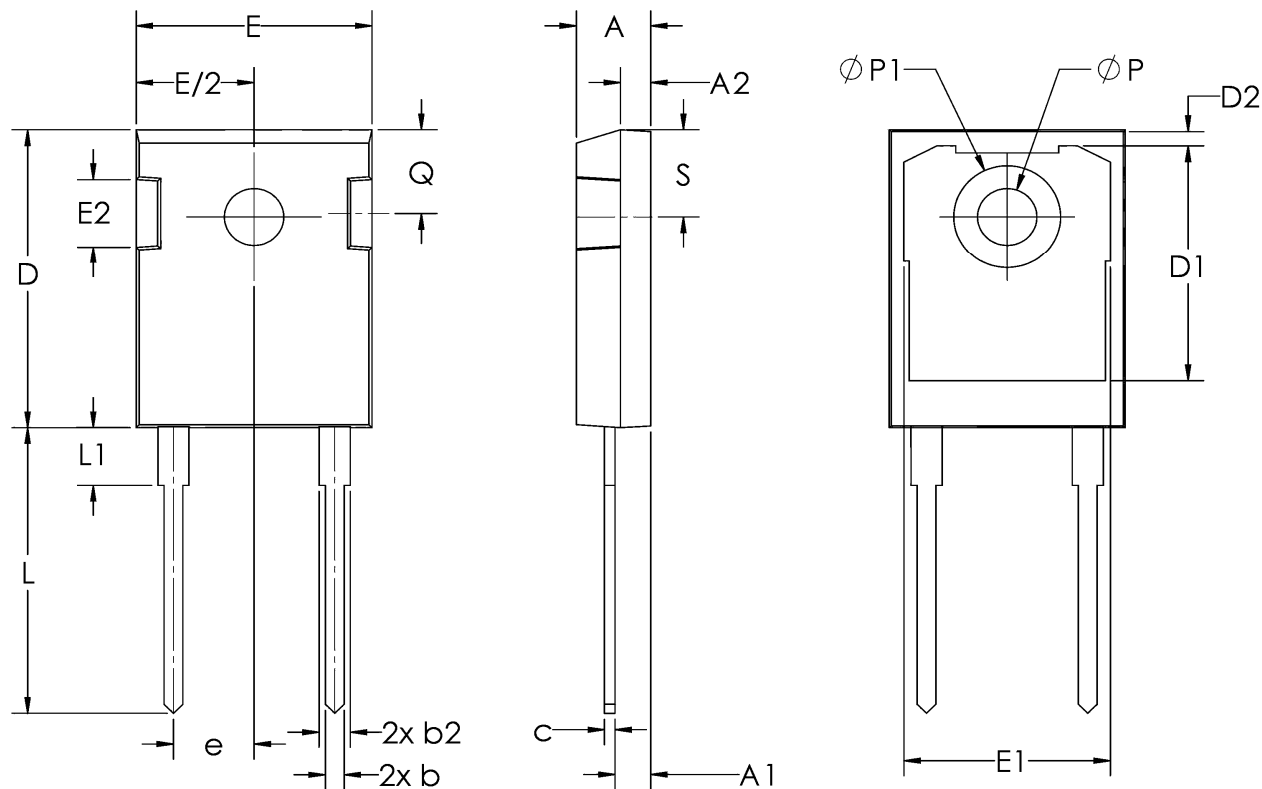
Fig. 6 Capacitance



QSiC™ 1700V SiC Schottky Di

GP3D050B170B

Package Dimensions TO-247-2L



Sym	Millimeters		Inches	
	Min	Max	Min	Max
A	4.70	5.31	0.185	0.209
A1	2.21	2.59	0.087	0.102
A2	1.50	2.49	0.059	0.098
b	0.99	1.40	0.039	0.055
b2	1.65	2.39	0.065	0.094
c	0.38	0.89	0.015	0.035
D	20.80	21.46	0.819	0.845
D1	13.08	17.65	0.515	0.695
D2	0.51	1.35	0.020	0.053
E	15.49	16.26	0.610	0.640
E1	13.46	14.16	0.530	0.557
E2	3.43	5.49	0.135	0.216
e	5.44 BSC		.214 BSC	
L	19.81	20.32	0.780	0.800
L1	4.10	4.50	0.161	0.177
ØP	3.56	3.66	0.140	0.144
ØP1	7.06	7.39	0.278	0.291
Q	5.38	6.20	0.212	0.244
S	6.04	6.30	0.238	0.248

Revision History

Date	Revision	Notes
7/23/2021	0.1	Initial release of preliminary datasheet
4/5/2024	0.2	Updated additional data, updated format
5/23/2024	0.3	Update part number

Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.SemiQ.com.

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REACH substances of high concern (SVHC) information is available for this product. Since the European Chemicals Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact our office at SemiQ Headquarters in Lake Forest, California to insure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

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